Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Milstar

Features Provided:

Electrostatic sensitive and radiation hardened and static operation and tested to mil-std-883

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Criticality Code Justification:

Feat and cbbl and nhcf

Case Outline Source And Designator:

D-9 mil-m-38510

Product Name:

Microcircuit, digital-2k x 8 bits, static ram

Voltage Rating And Type Per Characteristic:

-0.5 volts total supply and 7.0 volts total supply

Memory Device Type:

Ram

Special Features:

Esd and hci; rad hardness iaw: esd-82-te-1390b

Nuclear Hardness Critical Feature:

Hardened

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0